

PIN Diode Single PIN Diode for Attenuator and RF Switch

NSDP301MX2W, NSVDP301MX2W

Low rs characteristics is enable to use high frequency applications. This PIN diode is designed to realize compact and efficient designs. NSDP301MX2W in a X2DFNW2 miniature package enables designers to meet the challenging task of achieving higher efficiency and meeting reduced space requirements. In addition, wettable flank package improves the quality at mounted to PCB.

Features

- Low Series Resistance ($r_s = 1.3 \Omega \text{ typ.}$)
- Small Interterminal Capacitance (C = 0.33 pF typ.)
- Less Parasitic Components
- Small-sized Package
- Wettable Flank Package
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free and are RoHS Compliant

Typical Applications

- RF Attenuator
- RF Switch

MAXIMUM RATINGS $(T_A = 25^{\circ}C)$

Parameter	Symbol	Value	Unit
Reverse Voltage	V_{R}	80	V
Forward Current	I _F	100	mA
Operating Junction and Storage Temperature Range	T _J , T _{stg}	–55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

80 V, 100 mA rs = 1.3 Ω typ. PIN Diode





MARKING DIAGRAM



RG = Specific Device Code M = Date Code

ORDERING INFORMATION

	Device	Package	Shipping [†]
	NSDP301MX2WT5G	X2DFNW2 (Pb-Free)	8000 / Tape & Reel
İ	NSVDP301MX2WT5G	X2DFNW2 (Pb-Free)	8000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

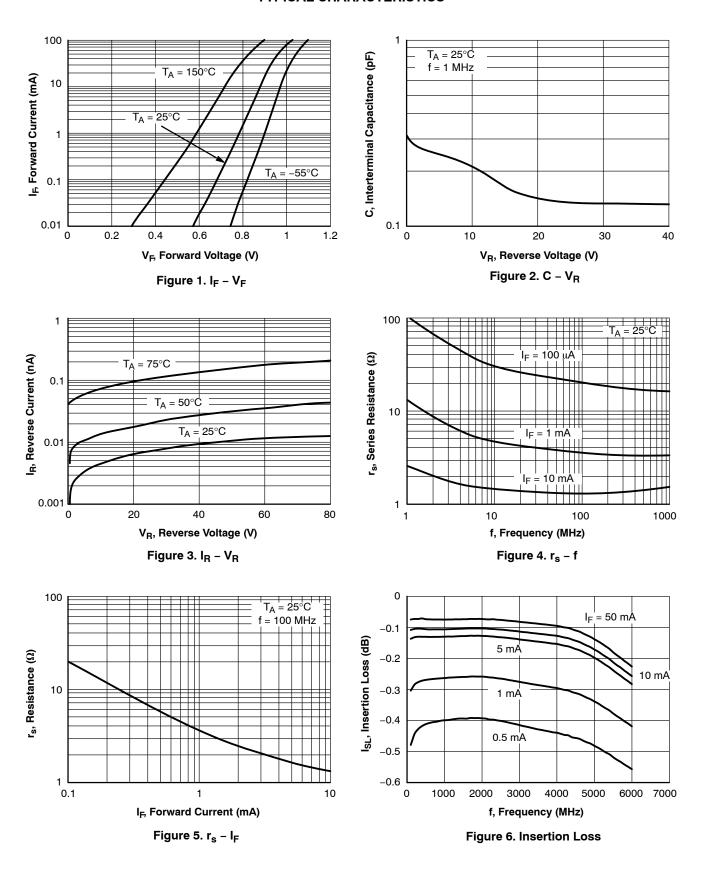
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Voltage	V_{R}	I _R = 1 μA	80			V
Reverse Current	I _R	V _R = 80 V			50	nA
Forward Voltage	V _F	I _F = 1 mA		0.78	0.81	V
Series Resistance	r _s	I _F = 10 mA, f = 100 MHz		1.3		Ω
Interterminal Capacitance	С	V _R = 0 V, f = 1 MHz		0.33		pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1

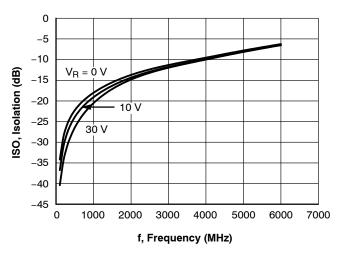
NSDP301MX2W, NSVDP301MX2W

TYPICAL CHARACTERISTICS



NSDP301MX2W, NSVDP301MX2W

TYPICAL CHARACTERISTICS (Continued)



0 -10 RL, Return Loss (dB) -20 $I_{F} = 0.5 \text{ mA}$ -30 -40 1 mA -50 -60 10 mA -70 1000 2000 3000 4000 7000 5000 f, Frequency (MHz)

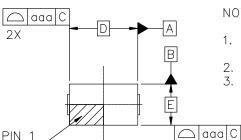
Figure 7. Isolation

Figure 8. Return Loss



X2DFNW-2 1.00x0.60x0.37, 0.65PCASE 711BG ISSUE F

DATE 06 NOV 2025



NOTES:

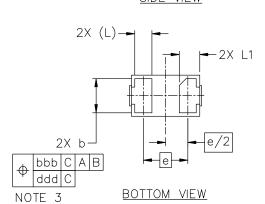
- I. DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5-2018.
- 2. ALL DIMENSION ARE IN MILLIMETERS.
- . DIMENSION 6 APPLIES TO THE PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 FROM THE TERMINAL TIP.

TOP VIEW

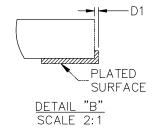
DETAIL B

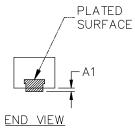
A



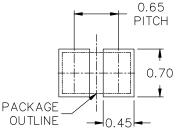


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MILLIMETERS					
DIM	MIN	NOM	MAX		
А	0.34	0.37	0.40		
Α1	2	2	0.05		
b	0.45	0.50	0.55		
D	1.00 BSC				
D1	2	2	0.05		
Е	0.60 BSC				
е	0.65 BSC				
L	0.22 REF				
L1	0.24	0.28	0.34		
TOLERANCE FORM & POSITION					
aaa	0.05				
bbb	0.10				
ccc	0.05				
ddd	0.05				
eee	0.05				



RECOMMENDED MOUNTING FOOTPRINT*

* FOR ADDITIONAL INFORMATION ON OUR Pb-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE onsemi SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



XX = Specific Device CodeM = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G", may or not be present. Some products may not follow the Generic Marking.

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DESCRIPTION:	X2DFNW-2 1.00x0.60x0.37, 0.65P		PAGE 1 OF 1	

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